

**K-no.:** 24620

**100 A Current Sensor Module for 5V- Supply Voltage**
**Date:** 14.07.2014

 For electronic current measurement:  
 DC, AC, pulsed, mixed ..., with a galvanic  
 isolation between primary circuit  
 (short power) and secondary circuit  
 (electronic circuit)

**Customer:** Standard type

**Customers Part no.:**

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**Description**

- Closed loop (compensation)  
Current Sensor with magnetic field probe
- Printed circuit board mounting
- Casing and materials UL-listed

**Characteristics**

- Excellent accuracy
- Very low offset current
- Very low temperature dependency and offset current drift
- Very low hysteresis of offset current
- Short response time
- Wide frequency bandwidth
- Compact design
- Reduced offset ripple

**Applications**

Mainly used for stationary operation in industrial applications:

- AC variable speed drives and servo motor drives
- Static converters for DC motor drives
- Battery supplied applications
- Switched Mode Power Supplies (SMPS)
- Power Supplies for welding applications
- Uninterruptible Power Supplies (UPS)

**Electrical data – Ratings**

$I_{PN}$	Primary nominal r.m.s. current	100	A
$V_{out}$	Output voltage @ $I_P$	$V_{Ref} \pm (0.625 \cdot I_P / I_{PN})$	V
$V_{out}$	Output voltage @ $I_P=0, T_A=25^\circ C$	$V_{Ref} \pm 0.0025$	V
$V_{Ref}$	External Reference voltage range	0...4	V
	Internal Reference voltage	$2.5 \pm 0.005$	V
$K_N$	Turns ratio	1...3 : 1100	

**Accuracy – Dynamic performance data**

		min.	typ.	max.	Unit
$I_{P,max}$	Max. measuring range	±200			
X	Accuracy @ $I_{PN}, T_A=25^\circ C$			0.7	%
$\epsilon_L$	Linearity			0.1	%
$V_{out} - V_{Ref}$	Offset voltage @ $I_P=0, T_A=25^\circ C$			±2.5	mV
$\Delta V_o / V_{Ref} / \Delta V$	Temperature drift of $V_{out}$ @ $I_P=0, T_A=-40...85^\circ C$		3	10	ppm/°C
$t_r$	Response time @ 90% von $I_{PN}$		500		ns
$\Delta t (I_{P,max})$	Delay time at $di/dt = 100 A/\mu s$		500		ns
f	Frequency bandwidth	DC...100			kHz

**General data**

		min.	typ.	max.	Unit	
$T_A$	Ambient operating temperature	-40		+85	°C	
$T_S$	Ambient storage temperature	-40		+85	°C	
m	Mass		15		g	
$V_C$	Supply voltage	4.75	5	5.25	V	
$I_C$	Current consumption		16		mA	
	Constructed and manufactured and tested in accordance with EN 61800-5-1 (Pin 1 - 6 to Pin 7 - 10) Reinforced insulation, Insulation material group 1, Pollution degree 2					
$S_{clear}$	Clearance (component without solder pad)	10.2			mm	
$S_{creep}$	Creepage (component without solder pad)	10.2			mm	
$V_{sys}$	System voltage	overvoltage category 3			600	$V_{RMS}$
$V_{work}$	Working voltage	(table 7 acc. to EN61800-5-1) overvoltage category 2			1020	$V_{RMS}$
$U_{PD}$	Rated discharge voltage				1400	$V_P$
	Max. potential difference acc. to UL 508	RMS			600	$V_{AC}$

Date	Name	Issue	Amendment
14.07.14	DJ	84	Sensor optimised. Marking updated. CN-981
25.04.13	KRe	83	Mechanical outline: marking with UL-sign and max potential difference added. CN-666

Hrsg.: KB-E editor	Bearb.: Le designer	KB-PM: Ga. check	freig.: HS released
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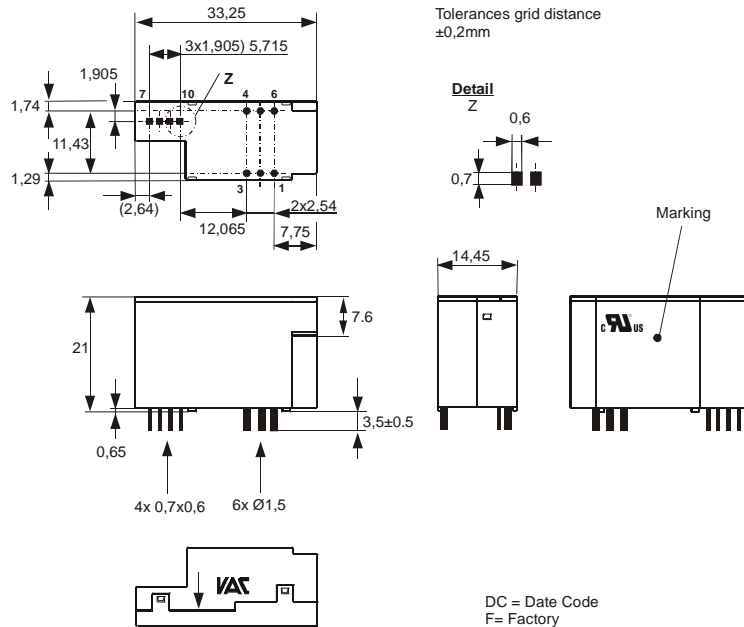
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**Mechanical outline (mm):**

General tolerances DIN ISO 2768-c



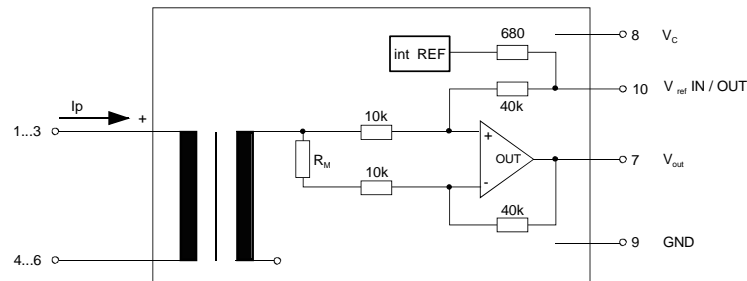
Connections:

1...6:  $\varnothing 1.5\text{ mm}$   
7..10:  $0.7 \times 0.6\text{ mm}$

Marking:

UL-sign  
4646-X461  
F DC

**Schematic diagram**



**Possibilities of wiring** (@  $T_A = 85^\circ\text{C}$ )

primary windings	primary current RMS	primary current maximal	output current RMS	turns ratio	primary resistance	wiring
$N_P$	$I_P$ [A]	$\hat{I}_{P,max}$ [A]	$I_S(I_P)$ [mA]	$K_N$	$R_P$ [m $\Omega$ ]	
1	100	$\pm 200$	$2.5 \pm 0.625$	1:1100	0.1	
2	50	$\pm 100$	$2.5 \pm 0.625$	2:1100	0.45	
3	33.3	$\pm 66$	$2.5 \pm 0.625$	3:1100	1	

Temperature of the primary conductor should not exceed  $100^\circ\text{C}$ .  
Additional information is obtainable on request.  
This specification is no declaration of warranty acc. BGB §443.

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**Electrical Data**

		min.	typ.	max.	Unit
$V_{Ctot}$	Maximum supply voltage (without function)			6	V
$I_C$	Supply Current with primary current	16mA + $I_p \cdot K_N + V_{out}/R_L$			mA
$I_{out,SC}$	Short circuit output current	±20			mA
$R_P$	Resistance / primary winding @ $T_A=25^\circ C$			0.3	mΩ
$R_S$	Secondary coil resistance @ $T_A=85^\circ C$			15	Ω
$R_{i,Ref}$	Internal resistance of Reference input	670			Ω
$R_{i,(V_{out})}$	Output resistance of $V_{out}$			1	Ω
$R_L$	External recommended resistance of $V_{out}$	1			kΩ
$C_L$	External recommended capacitance of $V_{out}$			500	pF
$\Delta X_{Ti}/\Delta V$	Temperature drift of X @ $T_A = -40 \dots +85^\circ C$			40	ppm/K
$\Delta V_0 = \Delta(V_{out} - V_{Ref})$	Sum of any offset drift including:		2	6	mV
$V_{0t}$	Longtermdrift of $V_0$		1		mV
$V_{0T}$	Temperature drift von $V_0$ @ $T_A = -40 \dots +85^\circ C$		1		mV
$V_{0H}$	Hystereses of $V_{out}$ @ $I_P=0A$ (after an overload of 10 x $I_{PN}$ )			0.5	mV
$\Delta V_0/\Delta V_C$	Supply voltage rejection ratio			1	mV/V
$V_{OSS}$	Offsetripple (with 1 MHz- filter first order)			21	mV
$V_{OSS}$	Offsetripple (with 100 kHz- filter first order)		3.5	6	mV
$V_{OSS}$	Offsetripple (with 20 kHz- filter first order)		1	1.5	mV
$C_k$	Maximum possible coupling capacity (primary – secondary)		5		pF
	Mechanical stress according to M3209/3 Settings: 10 – 2000 Hz, 1 min/Oktave, 2 hours			30g	

**Inspection** (Measurement after temperature balance of the samples at room temperature, SC = significant characteristic)

$V_{out}(SC)$	(V) M3011/6:	Output voltage vs. reference ( $I_P=3 \times 10 A_{Peak}$ , 40-80Hz)	625±0,7%	mV
$V_{out}-V_{Ref}$	(V) M3226:	Offset voltage ( $I_P=0A$ )	± 0.0025	V
$V_d$	(V) M3014:	Test voltage, 1 s pin 1 – 6 vs. pin 7 – 10	2.5	kV <sub>RMS</sub>
$V_e$	(AQL 1/54)	Partial discharge voltage acc.M3024 with $V_{vor}$	1500 1875	$V_{RMS}$ $V_{RMS}$

**Type Testing** (Pin 1 - 6 to Pin 7 – 10)

$V_W$	HV transient test according to M3064 (1,2 μs / 50 μs-wave form)	8	kV
$V_d$	Testing voltage to M3014 (5 s)	5	kV
$V_e$	Partial discharge voltage acc.M3024 with $V_{vor}$	1500 1875	$V_{RMS}$ $V_{RMS}$

**Applicable documents**

 Current direction: A positive output current appears at point  $V_{out}$ , by primary current in direction of the arrow.  
 Further standards UL 508 ; file E317483, category NMTR2 / NMTR8  
 Enclosures according to IEC529: IP50.

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14.07.14	DJ	84	Sensor optimised. CN-998
25.04.13	KRe	83	Applicable documents: further standards added. CN-666

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